

# Silicon Bridge Rectifier

$V_{RRM} = 50\text{ V} - 1000\text{ V}$   
 $I_F = 4\text{ A}$

## Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Types up to 1000 V  $V_{RRM}$
- Ideal for printed circuit board
- High surge current capability
- High temperature soldering guaranteed: 250°C/ 10 seconds, 0.375(9.5mm) lead length
- Glass passivated chip junction
- High case dielectric strength

## GBL Package



## Mechanical Data

Case: Molded plastic body over passivated junctions

Weight: 0.071 oz, 2 g

Mounting position: Any

Terminals: Plated leads, solderable per MIL-STD-750

Method 2026 guaranteed

## Maximum ratings, at $T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	GBL005	GBL01	GBL02	GBL04	Unit
Repetitive peak reverse voltage	$V_{RRM}$		50	100	200	400	V
RMS reverse voltage	$V_{RMS}$		35	70	140	280	V
DC blocking voltage	$V_{DC}$		50	100	200	400	V
Continuous forward current	$I_F$	$T_C \leq 25\text{ °C}$	4	4	4	4	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ °C}$ , $t_p = 8.3\text{ ms}$	150	150	150	150	A
Operating temperature	$T_j$		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	$T_{stg}$		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C

## Electrical characteristics, at $T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	GBL005	GBL01	GBL02	GBL04	Unit
Diode forward voltage	$V_F$	$I_F = 4\text{ A}$ , $T_j = 25\text{ °C}$	1.1	1.1	1.1	1.1	V
Reverse current	$I_R$	$V_R = 50\text{ V}$ , $T_j = 25\text{ °C}$	5	5	5	5	$\mu\text{A}$
		$V_R = 50\text{ V}$ , $T_j = 125\text{ °C}$	500	500	500	500	

## Thermal characteristics

Parameter	Symbol	GBL005	GBL01	GBL02	GBL04	Unit
Thermal resistance, junction - case	$R_{thJA}$	22.0	22.0	22.0	22.0	°C/W
	$R_{thJL}$	3.5	3.5	3.5	3.5	

